

SINGLE 2 INPUT POSITIVE AND GATE

Description

The 74LVCE1G08 is a single 2-input positive AND gate with a standard totem pole output. The device is designed for operation with a power supply range of 1.4V to 5.5V. The inputs are tolerant to 5.5V allowing this device to be used in a mixed voltage environment. The device is fully specified for partial power down applications using I_{OFF} . The I_{OFF} circuitry disables the output preventing damaging current backflow when the device is powered down.

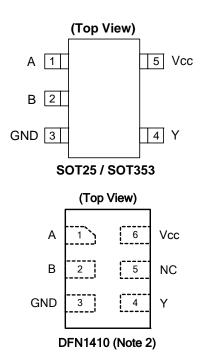
The gate performs the positive Boolean function:

$$Y = A \bullet B$$
 or $Y = \overline{\overline{A} + \overline{B}}$

Features

- Extended Supply Voltage Range from 1.4 to 5.5V
- Switching speed characterized for operation at 1.5V
- Offers 30% speed improvement over LVC at 1.8V.
- ± 24mA Output Drive at 3.3V
- CMOS low power consumption
- IOFF Supports Partial-Power-Down Mode Operation
- Inputs accept up to 5.5V
- ESD Protection Tested per JESD 22
 Exceeds 200-V Machine Model (A115-A)
 Exceeds 2000-V Human Body Model (A114-A)
- Latch-Up Exceeds 100mA per JESD 78, Class II
- Range of Package Options
- Direct Interface with TTL Levels
- SOT25, SOT353, and DFN1410: Available in "Green" Molding Compound (no Br, Sb)
- Lead Free Finish/ RoHS Compliant (Note 1)

Pin Assignments



Applications

- Voltage Level Shifting
- General Purpose Logic
- Wide array of products such as.
 - o PCs, networking, notebooks, netbooks, PDAs
 - o Computer peripherals, hard drives, CD/DVD ROM
 - o TV, DVD, DVR, set top box
 - o Cell Phones, Personal Navigation / GPS
 - o MP3 players ,Cameras, Video Recorders
- Notes: 1. EU Directive 2002/95/EC (RoHS). All applicable RoHS exemptions applied. Please visit our website at http://www.diodes.com/products/lead_free.html.
 - 2. Pin 2 and pin 5 of the DFN1410 package are internally connected.



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Pin Descriptions

| Pin Name | Description | | | |
|----------|----------------|--|--|--|
| А | Data Input | | | |
| В | Data Input | | | |
| GND | Ground | | | |
| Y | Data Output | | | |
| Vcc | Supply Voltage | | | |

Logic Diagram



Function Table

| Inp | Output | |
|-----|--------|---|
| Α | В | Y |
| Н | Н | Н |
| L | Х | L |
| Х | L | L |



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Absolute Maximum Ratings (Note 3)

| Symbol | Description | Rating | Unit |
|------------------|---|------------------------------|------|
| ESD HBM | Human Body Model ESD Protection | 2 | KV |
| ESD MM | Machine Model ESD Protection | 200 | V |
| V _{CC} | Supply Voltage Range | -0.5 to 6.5 | V |
| VI | Input Voltage Range | -0.5 to 6.5 | V |
| Vo | Voltage applied to output in high impedance or IOFF state | -0.5 to 6.5 | V |
| Vo | Voltage applied to output in high or low state | -0.3 to V _{CC} +0.5 | V |
| I _{IK} | Input Clamp Current V _I <0 | -50 | mA |
| Ι _{οκ} | Output Clamp Current | -50 | mA |
| Ι _Ο | Continuous output current | ±50 | mA |
| | Continuous current through Vdd or GND | ±100 | mA |
| TJ | Operating Junction Temperature | -40 to 150 | °C |
| T _{STG} | Storage Temperature | -65 to 150 | °C |

Note: 3. Stresses beyond the absolute maximum may result in immediate failure or reduced reliability. These are stress values and device operation should be within recommend values.

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Recommended Operating Conditions (Note 4)

| Symbol | | Parameter | Min | Max | Unit | |
|-----------------|--------------------------------|--|------------------------|-------------------------|------|--|
| V | | Operating | 1.4 | 5.5 | V | |
| V _{CC} | Operating Voltage | Data retention only | 1.2 | | V | |
| | | $V_{\rm CC} = 1.4$ V to 1.95 V | 0.65 X V _{CC} | | | |
| | | $V_{\rm CC}$ = 2.3 V to 2.7 V | 1.7 | | V | |
| V _{IH} | High-level Input Voltage | $V_{CC} = 3 V$ to 3.6 V | 2 | | V | |
| | | $V_{\rm CC} = 4.5 \text{ V to } 5.5 \text{ V}$ | 0.7 X V _{CC} | | | |
| | | $V_{\rm CC} = 1.4 \text{ V}$ to 1.95 V | | 0.35 X V_{CC} | | |
| V | | $V_{\rm CC} = 2.3 \text{ V to } 2.7 \text{ V}$ | | 0.7 | V | |
| V_{IL} | Low-level input voltage | $V_{CC} = 3 V$ to 3.6 V | | 0.8 | V | |
| | | $V_{\rm CC} = 4.5 \text{ V} \text{ to } 5.5 \text{ V}$ | | 0.3 X V _{CC} | | |
| VI | Input Voltage | | 0 | 5.5 | V | |
| Vo | Output Voltage | | 0 | V _{cc} | V | |
| | High-level output current | Vcc=1.4 V | | -3 | ~^^ | |
| | | V _{CC} = 1.65 V | | -4 | | |
| | | $V_{CC} = 2.3 V$ | | -8 | | |
| I _{OH} | | | | -16 | mA | |
| | | $V_{CC} = 3 V$ | | -24 | | |
| | | $V_{CC} = 4.5 V$ | | -32 | | |
| | | Vcc=1.4 V | | 3 | | |
| | | V _{CC} = 1.65 V | | 4 | | |
| | | $V_{CC} = 2.3 V$ | | 8 | mA | |
| I _{OL} | Low-level output current | | | 16 | | |
| | | $V_{CC} = 3 V$ | | 24 | | |
| | | $V_{CC} = 4.5 V$ | | 32 | | |
| | | $V_{CC} = 1.4 \text{ to } 3V$ | | 20 | | |
| Δt/ΔV | Input transition rise or fall | $V_{CC} = 3.3 \text{ V} \pm 0.3 \text{ V}$ | | 10 | ns/V | |
| | rate | $V_{\rm CC} = 5 \ V \pm 0.5 \ V$ | | 5 | | |
| T _A | Operating free-air temperature | | -40 | 85 | ٥C | |

Note: 4. Unused inputs should be held at Vcc or Ground.



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Electrical Characteristics (All typical values are at Vcc = 3.3V, T_A = 25°C)

| Over reco | mmended free-air tempera | ature range (unless of | therwise noted) | | | | |
|-------------------|---|---|-----------------|----------------|------|------|------|
| Symbol | Parameter | Test Conditions | Vcc | Min | Тур. | Max | Unit |
| | | I _{OH} = -100μA | 1.4 V to 5.5V | $V_{CC} - 0.1$ | | | |
| | | I _{OH} = -3mA | 1.4 V | 1.05 | | | |
| | | I _{OH} = -4mA | 1.65 V | 1.2 | | | |
| V _{OH} | High Level Output Voltage | I _{OH} = -8mA | 2.3V | 1.9 | | | V |
| | Voltage | I _{OH} = -16mA | 3 V | 2.4 | | | |
| | | I _{OH} = -24mA | 3 V | 2.3 | | | |
| | | I _{OH} = -32mA | 4.5 V | 3.8 | | | |
| | | I _{OL} = 100μA | 1.4 V to 5.5V | | | 0.1 | |
| | | I _{OL} = 3mA | 1.4 V | | | .4 | |
| | | $I_{OL} = 4mA$ | 1.65 V | | | 0.45 | V |
| V _{OL} | High-level Input Voltage | I _{OL} = 8mA | 2.3V | | | 0.3 | |
| | | I _{OL} = 16mA | 3 V | | | 0.4 | |
| | | $I_{OL} = 24 \text{mA}$ | 5 V | | | 0.55 | |
| | | $I_{OL} = 32 \text{mA}$ | 4.5 | | | 0.55 | |
| I, | Input Current | $V_1 = 5.5 \text{ V or GND}$ | 0 to 5.5 V | | | ± 5 | μA |
| I _{OFF} | Power Down Leakage Current | $V_1 \text{ or } V_0 = 5.5 V$ | 0 | | | ± 10 | μA |
| I _{CC} | Supply Current | $V_1 = 5.5V \text{ of GND}$ $I_0=0$ | 1.4 V to 5.5V | | | 10 | μA |
| ΔI _{CC} | Additional Supply Current | One input at V_{CC} – 0.6 V Other inputs at V_{CC} or GND | 3 V to 5.5V | | | 500 | μA |
| Ci | Input Capacitance | $V_i = V_{CC} - or GND$ | 3.3 | | 3.5 | | pF |
| | | SOT25 | (Note 5) | | 204 | | |
| θ_{JA} | Thermal Resistance Junction-to-Ambient | SOT353 | (Note 5) | | 371 | | °C/W |
| | | DFN1410 | (Note 5) | | 430 | | 1 |
| | | SOT25 | (Note 5) | | 52 | | |
| $\theta_{\rm JC}$ | Thermal Resistance Junction-to-Case | SOT353 | (Note 5) | | 143 | | °C/W |
| | 5011011-10-0858 | DFN1410 | (Note 5) | | 190 | | |
| | | 1 | | 1 | | | 1 |

Note: 5. Test condition for SOT25, SOT353, and DFN1410: Device mounted on FR-4 substrate PC board, 2oz copper, with minimum recommended pad layout.



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Switching Characteristics

| Parameter From | | ТО | ± 0 | | | : 1.8 V .15V | | : 2.5 V).2V | | : 3.3 V).3V | | = 5 V).5V | Unit |
|-----------------|---------|----------|-----|-----|-----|-----------------|-----|-----------------|-----|-----------------|-----|---------------|------|
| | (Input) | (OUTPUT) | Min | Max | Min | Max | Min | Max | Min | Max | Min | Max | |
| t _{pd} | A or B | Y | 1.5 | 7.2 | 1.0 | 5 | 0.5 | 3.5 | 0.6 | 2.9 | 0.7 | 2.9 | ns |

Over recommended free-air temperature range, CL = 15pF (see Figure 1)

Over recommended free-air temperature range, CL = 30 or 50pF as noted (see Figure 2)

| Parameter From TO | | | Vcc = ± 0 | | | : 1.8 V .15V | | : 2.5 V).2V | Vcc = ± 0 | : 3.3 V).3V | Vcc ± 0 | = 5 V).5V | Unit |
|-------------------|---------|----------|--------------|-----|-----|-----------------|-----|-----------------|--------------|-----------------|------------|---------------|------|
| | (Input) | (OUTPUT) | Min | Max | Min | Max | Min | Max | Min | Max | Min | Max | • |
| t _{pd} | A or B | Y | 2.4 | 8 | 1.6 | 5.6 | 0.8 | 4.4 | 0.8 | 3.6 | 0.9 | 3.6 | ns |

Operating Characteristics

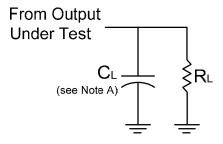
 $T_A = 25 \ ^{o}C$

| Р | arameter | | Vcc = 1.5 V | Vcc = 1.8 V | Vcc = 2.5 V | Vcc = 3.3 V | Vcc = 5 V | Unit |
|----------|-------------------------------------|------------|-------------|-------------|-------------|-------------|-----------|-------|
| - | Conc | | TYP | ТҮР | ТҮР | TYP | TYP | ••••• |
| C_{pd} | Power dissipation capacitance | f = 10 MHz | 21 | 21 | 24 | 26 | 31 | pF |

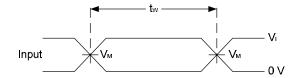


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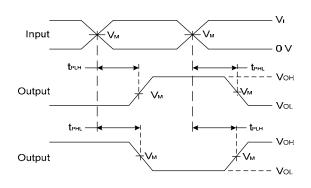
Parameter Measurement Information



| Vcc | In | puts | V., | C. | Р. | |
|------------|-----------------|--------------------------------|--------------------|------|-----|--|
| VCC | VI | t _r /t _f | V _M | CL | RL | |
| 1.5V±0.1V | V _{CC} | ≤2ns | V _{CC} /2 | 15pF | 1MΩ | |
| 1.8V±0.15V | V _{cc} | ≤2ns | V _{CC} /2 | 15pF | 1MΩ | |
| 2.5V±0.2V | V _{cc} | ≤2ns | V _{CC} /2 | 15pF | 1MΩ | |
| 3.3V±0.3V | 3V | ≤2.5ns | 1.5V | 15pF | 1MΩ | |
| 5V±0.5V | V _{CC} | ≤2.5ns | V _{CC} /2 | 15pF | 1MΩ | |



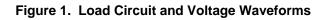
Voltage Waveform Pulse Duration



Voltage Waveform Propagation Delay Times Inverting and Non Inverting Outputs

Notes: A. Includes test lead and test apparatus capacitance.

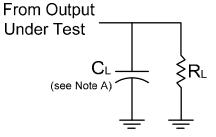
- B. All pulses are supplied at pulse repetition rate \leq 10 MHz.
- C. Inputs are measured separately one transition per measurement.
- D. t_{PLH} and t_{PHL} are the same as $t_{PD.}$



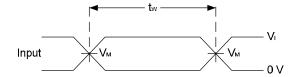


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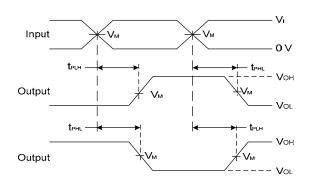
Parameter Measurement Information (Continued)



| Vcc | Inputs | | V _M | CL | RL | |
|------------|-----------------|--------------------------------|--------------------|------|------|--|
| | Vı | t _r /t _f | - 141 | υĽ | | |
| 1.5V±0.1V | V _{cc} | ≤2ns | V _{CC} /2 | 30pF | 1KΩ | |
| 1.8V±0.15V | V _{CC} | ≤2ns | V _{CC} /2 | 30pF | 1KΩ | |
| 2.5V±0.2V | V _{cc} | ≤2ns | V _{CC} /2 | 30pF | 500Ω | |
| 3.3V±0.3V | 3V | ≤2.5ns | 1.5V | 50pF | 500Ω | |
| 5V±0.5V | V _{CC} | ≤2.5ns | V _{CC} /2 | 50pF | 500Ω | |



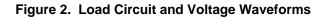
Voltage Waveform Pulse Duration



Voltage Waveform Propagation Delay Times Inverting and Non Inverting Outputs

Notes: A. Includes test lead and test apparatus capacitance.

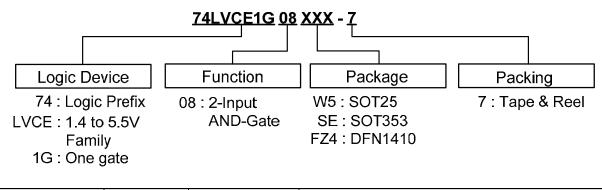
- B. All pulses are supplied at pulse repetition rate ≤ 10 MHz.
- C. Inputs are measured separately one transition per measurement.
- D. t_{PLH} and t_{PHL} are the same as $t_{PD.}$





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Ordering Information



| | Device | Package | Packaging | 7" Tape and Reel | | |
|-------------|-----------------|---------|-----------|------------------|--------------------|--|
| | Device | Code | (Note 5) | Quantity | Part Number Suffix | |
| Pb , | 74LVCE1G08W5-7 | W6 | SOT25 | 3000/Tape & Reel | -7 | |
| Pb , | 74LVCE1G08SE-7 | SE | SOT353 | 3000/Tape & Reel | -7 | |
| P , | 74LVCE1G08FZ4-7 | FZ4 | DFN1410 | 5000/Tape & Reel | -7 | |

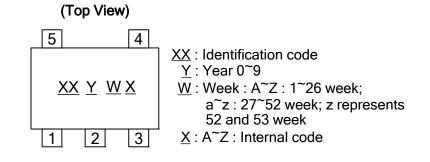
Note: 6. Pad layout as shown on Diodes Inc. suggested pad layout document AP02001, which can be found on our website at http://www.diodes.com/datasheets/ap02001.pdf.



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Marking Information

(1) SOT25 and SOT353



| Part Number | Package | Identification Code |
|--------------|---------|---------------------|
| 74LVCE1G08W5 | SOT25 | PV |
| 74LVCE1G08SE | SOT353 | PU |

(2) DFN1410H4-6

(Top View)



XX : Identification Code

<u>Y</u> : Year : 0~9

<u>W</u>: Week : A~Z : 1~26 week; a~z : 27~52 week; z represents 52 and 53 week

X : A~Z : Internal code

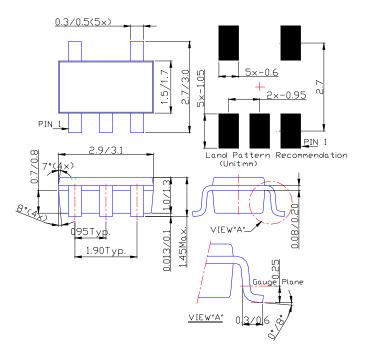
| Part Number | Package | Identification Code |
|---------------|---------|---------------------|
| 74LVCE1G08FZ4 | DFN1410 | PV |



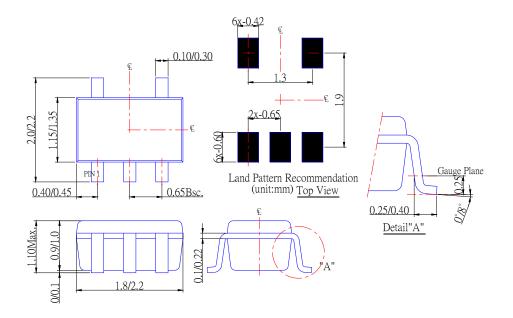
SINGLE 2 INPUT POSITIVE AND GATE

Package Outline Dimensions (All Dimensions in mm)

(1) Package Type: SOT25



(2) Package Type: SOT353



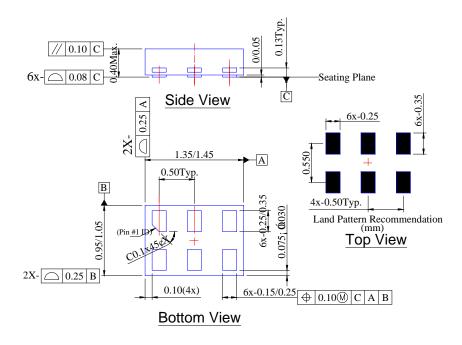
74LVCE1G08 Document number: DS32213 Rev. 2 - 2



SINGLE 2 INPUT POSITIVE AND GATE

Package Outline Dimensions (All Dimensions in mm)

(3) Package Type: DFN1410

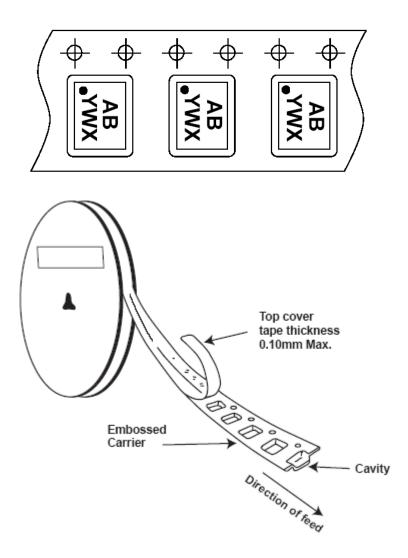




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Taping Orientation (Note 7)

For DFN1410







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